

## **APPENDIX A**

### **Abbreviations**

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ADC	Analog to Digital Converter
APD	Active Pixel Detector
ASIC	Application Specific Integrated Circuit
BNL	Brookhaven National Laboratory
CCD	Charge Coupled Device
CMOS	Complementary-MOS
EMC	EletroMagnetic Calorimeter
GPIB	General Purpose Interface Board
HV	High Voltage
LASER	Light Amplification Stimulated by Emission of Radiation
LHC	Large Hadron Collider, at CERN
MIP	Minimum ionizing particle
MOS	Metal-Oxide-Semiconductor
NTD	Neutron Transmutation Doped, silicon type.
PASA	Pre-amplifier/Shaper
PC-board	Printed Circuit board
QCD	Quantum ChronoDynamics
QGP	Quark-Gluon Plasma
RDO	ReadOut board
RHIC	Relativistic Heavy-Ion Collider, at BNL
SBSD	Surface Barrier Silicon Detector
SCA	Switched-Capacitor Array
SDD	Silicon Drift Detector
STAR	Solenoidal Tracker at RHIC
SVT	Silicon Vertex Tracker
TOF	Time Of Flight , detector
TPC	Time Projection Chamber

## **APPENDIX B**

### **Some constants and properties of semiconductors**

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Some physical properties of silicon and germanium

	Si	Ge
Atomic number Z	14	32
Atomic weight A	28.1	72.6
Density [g/cm <sup>2</sup> ]	2.33	5.32
Dielectric constant (relative)	11.9	16.0
Intrinsic resistivity (300K) [Ωcm]	230000	45
Energy gap (300K) [eV]	1.1	0.7
Energy gap (0K) [eV]	1.21	0.785
Electron mobility (300K) [cm <sup>2</sup> /Vs]	1350	3900
Hole mobility (300K) [cm <sup>2</sup> /Vs]	480	1900
Lattice constant (300K)[Å]	5.4309	5.6461

## **APPENDIX C**

### **STAR/SVT –SDD dimensions & specifications**

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The STAR silicon drift detectors were fabricated using a 3-inch diameter,  $280\pm20\text{-}\mu\text{m}$  thick, double sided polished n-type Wacker silicon wafer. The silicon wafers were doped using the neutron transmutation process (NTD) and the resistivity of the wafer was  $3\text{-}k\Omega\cdot\text{cm}$ . The minority carrier lifetime after oxidation was estimated to be about  $3\text{-msec.}$ , the interface state density was  $1.3\times10^{10}/\text{cm}^2$  and the oxide charge density about  $2.1\times10^{11}/\text{cm}^2$ .

#### **Single detector dimensions**

Detector total area:	$63\times63 \text{ mm} = 3969 \text{ mm}^2$
Detector area mounted in the SVT:	$3796 \text{ mm}^2$
Detector active area:	$2* 177.21 \text{ mm}^2 = 3554.4$
Inactive area:	$241.6 \text{ mm}^2 - 6.4 \text{ \%}$

#### **Cathodes:**

Pitch:	$135 \text{ }\mu\text{m}$
Width of the implanted strip:	$99 \text{ }\mu\text{m}$
Width of the aluminum overlay:	$120 \text{ }\mu\text{m}$

#### **Guard lines:**

Pitch:	$100 \text{ }\mu\text{m}$
Width of the implanted strip:	$10 \text{ }\mu\text{m}$
Width of the aluminum overlay:	$60 \text{ }\mu\text{m}$

#### **Injector line positions:**

1 <sup>st</sup> :	$2.285 \text{ mm}$
2 <sup>nd</sup> :	$9.975 \text{ mm}$
3 <sup>rd</sup> :	$19.695 \text{ mm}$
4 <sup>th</sup> :	$29.955 \text{ mm}$

## **REFERENCES**

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- [1.1] S.M. Sze, "Physics of Semiconductor Devices", Wiley-Interscience, New York (1981).
- [1.2] G.F. Knoll, "Radiation detection and measurement", 2<sup>nd</sup> Ed., John Wiley & Sons, 1989.
- [1.3] The STAR Collaboration, "Proposal for a Silicon Vertex Tracker (SVT) as an upgrade for the STAR experiment at RHIC", Berkeley, CA (1995).
- [1.4] Conceptual Design of the Relativistic Heavy Ion Collider, Report BNL 52195 (1989).
  
- [2.1] W. Shockley, "The theory of p-n junctions in semiconductors and p-n junction transistors", *Bell Syst. Tech. J.*, **28**, 435 (1949); *Electrons and Holes in Semiconductors*, D. Van Nostrand, Princeton, N. J., 1950.
- [2.2] C. T. Sah, R. N. Noyce, and W. Shockley, "Carrier Generation and Recombination in p-n junction and p-n junction characteristics", *Proc. IRE*, **45**, 1228 (1957).
- [2.3] G. Hall, "Ionization Energy losses of highly relativistic charged particles in thin Silicon layers", *Nucl. Inst. and Meth.*, **220** (1984) 356-362.
- [2.4] J.F. Bak, *et al.*, "Large Departures from Landau distributions for high-energy particles traversing thin Si and Ge targets", *Nucl. Phys.*, **B288** (1987) 681-716.
- [2.5] Review of Particle Properties - Particle Data Group, *Phys. Lett.*, **B170** (1986) 1-350.
- [2.6] E. Laegsgaard, *Nucl. Inst. and Meth.*, **162** (1979) 93.
- [2.7] B. Hyams, *et al.*, *Nucl. Inst. and Meth.*, **205** (1983) 99.
- [2.8] C. Colledani, *et al.*, "A submicron precision Silicon telescope for beam-test purposes", *Nucl. Inst. and Meth.*, **A372** (1996) 379.
- [2.9] ATLAS, Technical Proposal for a general-purpose pp experiment at the Large Hadron Collider at CERN, CERN/LHCC/94-43.

- [2.10] W. S. Boyle and G. E. Smith, *Bell Syst. Tech. Journal*, **49** (1970) 587.
- [2.11] R. H. Walden, *et al.*, *Nucl. Inst. and Meth.*, **51** (1972) 1635.
- [2.12] C. J. S. Damerell, *et al.*, *Nucl. Inst. and Meth.*, **185** (1981) 33.
- [2.13] C. J. S. Damerell, *et al.*, “Design and performance of the SLD vertex detector: a 307 Mpixel tracking system”, *Nucl. Inst. and Meth.*, **A400** (1997) 287-343.
- [2.14] P. Middelkamp, “Tracking with active pixel detectors”, Thesis at Fachbereich Physik Bergische Univ., Germany, (1996).
- [2.15] E. H. M. Heijne, P. Jarron, “Development of Silicon pixel detectors”, *Nucl. Inst. and Meth.*, **A275** (1989) 484.
- [2.16] G. Vanstraelen, “Monolithic integration of solid-state particle detectors and readout electronics on high resistivity Silicon”, Thesis at the Katholieke Univ. Leuven, Belgium, (1990).
- [2.17] E. Gatti and P. Rehak, Semiconductor Drift Chamber – An Application of a Novel Charge Transport Scheme, *Nucl. Inst. and Meth.*, **255** (1984) 608.
  
- [3.1] T.D. Lee, *Nucl. Phys.* **A590** (1995) 11c-28c.
- [3.2] J.C. Collins and M.J. Perry, *Phys. Rev. Lett.* **34**, 1353 (1975).
- [3.3] G. Chapline and M. Nauenberg, *Phys. Rev.* **D16**, 450 (1977).
- [3.4] J. Kapusta, *Nucl. Phys.* **61**, 461 (1980); H. Satz, *Ann. Rev. Nucl. Part. Sci.* **35**, 245 (1985).
- [3.5] J. W. Harris and the STAR Collaboration, “The STAR Experiment at the Relativistic Heavy Ion Collider”, *Nucl. Phys.*, **A566** (1994) 277c.
- [3.6] “Proposal for a Silicon Vertex Tracker (SVT) as an upgrade for the STAR experiment at RHIC”, Berkeley CA: The STAR Collaboration, (feb. 1995).
- [3.7] M. Tanenbaum and A. D. Mills, *J Electrochem. Soc.*, Vol 108, (1961) 171-176.

- [3.8] Larrabee, R.D., "Neutron Transmutation Doping of Semiconductor Materials", Plenum Press, New York and London, (1984).
- [3.9] G. Vilkelis, "Silicon Drift Detector R&D for the STAR Experiment at RHIC", Thesis at Univ. of Pittsburg, (1995).
- [3.10] W. Chen *et al.*, "Fabrication of Large Area Si Cylindrical Drift Detectors", *Trans. on Nucl. Sci.*, **Vol. 41**, NO.4, (1994).
- [3.11] P. Zahnt, "Microchip Fabrication: A practical guide to semiconductor processing", McGraw-Hill, NY, 2<sup>nd</sup> Ed. (1990).
- [3.12] R. Bellwied and the STAR/SVT Collaboration, "Development of Large Linear Silicon Drift Detectors for the STAR Experiment at RHIC", *Nucl. Inst. and Meth.*, **A377** (1996) 387-392.
- [3.13] R. Bellwied and the STAR/SVT Collaboration, "Anode Region Design and Focusing Properties of STAR Silicon Drift Detectors", *Nucl. Inst. and Meth.*, **A400** (1997) 279-286.
- [3.14] SILVACO International. 2D Device simulation framework.
- [3.15] N.W. Wang *et al.*, "P-type Silicon Drift Detectors: First Results", IEEE Trans., Augst, 1995.
- [3.16] E. Gatti *et al.*, "Electron injection in Semiconductor Drift Chambers", *Nucl. Inst. and Meth.*, **A295** (1990) 489-491.
- [3.17] R. Bellwied and the STAR/SVT Collaboration, "Electron Injection in Semiconductor Drift Detectors", to be published in *Nucl. Inst. and Meth.* (1998) in print.
  
- [4.1] J. Takahashi *et. al.*, "Silicon Drift Detectors for the STAR/SVT experiment at RHIC", submitted to *Nucl. Phys. and Meth.* (1998).
- [4.2] ANSI/IEEE std. 488.1-1987, "IEEE Standard Digital Interface for Programmable Instrumentation"; E-mail to [gpiib.support@natinst.com](mailto:gpiib.support@natinst.com)
- [4.3] S.M. Sze, D.J. Coleman, and A. Loya, "Current Transport in Metal-Semiconductor-Metal (MSM) Structures", *Solid State Electron*, **14**, 155 (1978).

- [4.4] E. Gatti and P.F. Manfredi. *Revista Nuovo Cimento*, **9**, 1 (1986).
- [4.5] W.C. Sailor, et al. *Nucl. Phys. and Meth.*, **A303**, (1991) 285.
- [4.6] S.U. Pandey *et al.*, “Two particle resolutions and Interactions in Silicon drift detectors”, *IEEE Transactions on Nuclear Science*, in press. (1998)
  
- [5.1] P. Rehak *et. al.*, “Electron injection in semiconductor drift detectors”, *IEEE Trans.*, (1990).
  
- [6.1] Proposal to the SPSLC, CERN SPSLC/94-1/P280.
- [6.2] R. Baur *et al.*, *Nucl. Inst. Meth.*, **A343** (1994) 87.
- [6.3] P. Donni *et al.*, “Proposal for a Large Acceptance Hadron and Photon Spectrometer”, CERN, Geneva, CERN-SPSLC-91-17 (1991/05, rec. Jul.) 87.
- [6.4] M Jacob and H. Satz, Proc. Bielefeld Workshopp, Quark Matter Formation and Heavy Ion Collisons, (World Scientific, Singapore, 1982).
- [6.5] T. Ludlam and H. Wegner, Proc. Third Int. Conf. on Ultra-Relativistic Nucleus-Nucleus Collisions, Quark Matter '83, *Nucl. Phys.* **A418** (1984).
- [6.6] E. V. Shuryak, *Phys. Rev.* **61**, 71 (1980).
- [6.7] H Staz, *Ann. Rev. Nucl. Part. Sci.* **35**, 245 (1985).
- [6.8] J. Cleymans *et al.*, *Phys. Rep.* **130**, 217 (1986).
- [6.9] G. Q. Li, C.M. Ko and G.E. Brown, *Phys. Rev. Lett.*, **75**, (1995) 35.
- [6.10] W. Cassing, W. Ehehalt and C.M. Ko, *Phys. Lett.*, **B363** (1995) 35.
- [6.11] W. Chen *et al.*, “Large Area Cylindrical Silicon Drift Detector”, Proc. 1991 IEEE Nuclear Science Symposium, Nov. 2, Santa Fe, USA.
- [6.12] W. Chen *et al.*, “Performance of the multianode cylindrical Silicon drift detector in the NA45 experiment: first results”, *Nucl. Phys. and Meth. in Phys. Res.* 00 (1992) NIM3051M.

- [6.13] T. Awes and WA98 Collaboration, “Photon and Neutral Meson production in 158 AGeV  $^{208}\text{Pb}+^{208}\text{Pb}$  collisions”, *Nucl. Phys.* **A610** (1996) 200c-212c.
- [6.14] Krishna Rajagopal. In Hwa, editor, *Quark-Gluon Plasma 2*. World Scientific, 1995.
- [6.15] K.L. Kowalski, J.D. Bjorken and C.C. taylor, SLAC-PUB-6109, 1993.
- [6.16] A.Anselm and M.G. Ryskin, *Phys. Lett.*, **B266** (1991) 482.
- [6.17] T. Brooks *et. al.*, “Analysis of Charged-Particle/Photon Correlations in Hadronic Multiparticle Production”, *Phys. Rev. D*, submitted.; See also “<http://fnmine.fnal.gov>”.
- [6.18] WA98 Collaboration, “Search for Disoriented Chiral Condensates in 158 AGeV Pb+Pb Collisions”.
- [7.1] H. Crawford and E896 Collaboration, Proposal 896 for the BNL-AGS, “Search for a short-lived  $\text{H}_0$  dibaryon, short-lived strange matter, and to investigate hyperon production in 11.6 GeV/c/N Au+Au collisions”.
- [7.2] W. J. Lope “The BNL-AGS Experiment 896”, 12<sup>th</sup> Winter Workshop on Nuclear Dynamics proceedings, Snowbird, Utah, 1996, plenum press, New York, N.Y.
- [7.3] R.L. Jaffe, “Perhaps a Stable Dihyperon”, *Phys. Rev. Lett.* **38** (1977) 195.
- [7.4] E. Farhi and R.L. Jaffe, *Phys. Rev.* **D30** (1984) 2379.
- [7.5] T. Saito *et. al.*, “Is there strange-Quark Matter in Galactic Cosmic Rays?”, *Phys. Rev. Lett.*, **V.65**, No.17, 2094 (1990); P. Haensel *et. al.*, *Astron. Astrophys.*, **160**, 121 (1986); *Astrophys. J.*, **310**, 261 (1986).
- [7.6] A. P. Balachandran, F. Lizzi, V.G.J. Rodgers and Stern, *Phys. Rev. Lett.* **52**, 887 (1984); E. Golowich and T. Sotirelis, *Phys. Rev.* **D46**, 354 (1992); P.B. Mackenzie and H.B. Thacker, *Phys. Rev. Lett.* **55**, 2539 (1985).
- [7.7] J. F. Donoghue, E. Golowich, and B.R. Holstein, *Phys. Rev.* **D34**, 3434 (1986).

- [7.8] H.R. Gustafson *et al.*, Phys. Rev. Lett. **37**, 474 (1976); A.S. Carroll *et. al.*, *ibid.* **41**, 777 (1978); S. Aoki *et al.*, *ibid.* **65**, 1729 (1990); B.A. Shahbazian *et al.*, Z. Phys. **C39**, 151 (1998).
- [7.9] J. Beltz *et al.*, Phys. Rev. Lett., **76**, 3277 (1996).
- [7.10] A. Swartz, “Searching for the H Dibarion at Brookhaven”, Princeton preprint Princeton/HEP/93-08.
- [7.11] J. Beltz *et al.* (BNL-AGS E888), Princeton University preprints 95-11 and 95-12 (1991); *ibid.*, **85**, 1287 (1991).
- [7.12] R. Longacre *et al.* (BNL-AGS E810), Nucl. Phys. **A590**, 477c (1995).
- [7.13] G. Levinson, “Dicing Through Hard and Brittle Materials in the Micro Electronics Industry”, Micro-Swiss internal publication.
- [7.14] J. Schambach *et al.*, “Data Acquisition Systems for E896 at the AGS”.
- [7.15] R. Bellwied<sup>a</sup>, H. Caines<sup>e</sup>, H. Dyke<sup>e</sup>, Y. Guo<sup>a</sup>, J. Hall<sup>a</sup>, J. Hoffmann<sup>c</sup>, T. Humanic<sup>e</sup>, P. Jensen<sup>c</sup>, I. Kotov<sup>e</sup>, P. Kuczewski<sup>b</sup>, B. Leonhardt<sup>b</sup>, C. Liaw<sup>b</sup>, G. LoCurto<sup>e</sup>, D. Lynn<sup>b</sup>, N. Mazeh<sup>a</sup>, P. Middelkamp<sup>b</sup>, B. Minor<sup>d</sup>, S. Nehmeh<sup>a</sup>, G. Ott<sup>c</sup>, S. Pandey<sup>a</sup>, C. Pruneau<sup>a</sup>, V. Rykov<sup>a</sup>, J. Schambach<sup>c</sup>, J. Sedlmeir<sup>b</sup>, J. Sheen<sup>a</sup>, B. Soja<sup>b</sup>, E. Sugarbaker<sup>e</sup>, J. Takahashi<sup>a,f</sup>, K. Wilson<sup>a</sup>; *a*. Wayne State University, *b*. Brookhaven National Laboratory, *c*. University of Texas, *d*. Lawrence Berkeley Laboratory, *e*. The Ohio State University, *f*. Universidade de São Paulo.
- [7.16] T. Schlagel *et. al.*, Phys. Rev. Lett. **68**, 2743 (1992), S. H. Kahana *et. al.*, Ann. Rev. of Nucl. and Part. Sci. **46** (1996).
- [7.17] H. Sorge, Nucl. Phys. **A630** (1998) 522 and Phys. Rev. **C52** (1995) 3291.
- [7.18] R. Bellwied and the SDDA-Collaboration, “The Performance of the SVT-SDDs in AGS Experiment 896”, STAR Note #321, January, 1998.
- [7.19] D.M. Reed, “The Silicon Drift Detector and its use in a vertex tracker” PhD Thesis dissertation, University of Texas, Austin, May 1996.
- [7.20] R. Bellwied *et al.*, “Double Particle Resolution in STAR Silicon Drift Detectors”, IEEE transactions on Nuclear Science, **V44**, N3 (1997) 687-690.
- [7.21] D.E. Kahana *et. al.*, Phys. Rev. **C54** (1996) 338.

- [7.22] R. Brun *et. al.*, *GEANT 3.12 User's Guide*, CERN DATA Handling Division, DD/EE/84-1; “GEANT-Detector and Simulation Tool”, CERN, PM0062 (1993).
- [8.1] L. Landau, *J. Phys.*, (USSR), **8** (1944) 201.
- [8.2] P.V. Vavilov, *Zh. Eksp. Teor. Fiz.*, **32**, 920 (1957); *Sov. Phys. JETP* **5**, 749 (1957).
- [8.3] S.T. Butler and C.A. Pearson, *Phys. Rev. Lett.* **7** (1961) 69; and *Phys. Rev.* **129** (1963) 836.
- [8.4] A. Schwarzschild and C. Zupancic, *Phys. Rev.* **129**, (1963) 854.
- [8.5] N. George, “PhD thesis – experiment E864”, in development.
- [9.1] E.H. Putley, “The Hall effect and Related Phenomena”, Whitefriars Press., Betterworth, 1960.
- [9.2] E.H. Hall, *Amer. J. Math.*, **2** (1879), 287.
- [9.3] F.J. Morin and J.P. Maita, “Electrical properties of silicon containing arsenic and boron”, *Phys. Rev.*, vol. 96, 1954 pp. 28-35.
- [9.4] J. Messier and J.M. Flores, *J. Phys. Chem. Solids*, vol. 24, 1963 pp.1539.
- [9.5] S.U. Pandey *et. al.*, “Transport Properties of electrons in Silicon Drift Detectors measured in large magnetic fields”, *Nucl. Inst. and Meth.*, **A383**, (1996) 537-546.
- [9.6] M. Clemen *et. al.*, “Hall effect measurements in a Silicon Drift Chamber”, in print.
- [9.7] W. Jones and N.H. March, “Theoretical Solid State Physics”, Vol.2, Dover Publ., New York.
- [9.8] G.L. Pearson and C. Herring, *Physica's Grav.*, **20**, (1954) 975.